

	L #	Hits	Search Text	DBs
1	L1	15377	(active near pixel near sensor) or APS	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	L3	417	(reset near transistor) same (select\$3 near transistor) same (source near follower)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	L4	334	pixel\$1 same 3	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	L5	185	1 and 4	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	L #	Hits	Search Text	DBs
5	L6	273	3 same gate\$1	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
6	L7	184	1 and 6	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
7	L8	38871	solid near state near imag\$3	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
8	L9	25	7 and 8	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	L #	Hits	Search Text	DBs
9	L10	14	narumi near ohkawa	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
10	L11	12	("4636865" "5144447" "5237190" "5243180" "5280186" "5338948" "5418387" "5517043" "5600159" "5867215" "6107655" "6160281").PN.	US- PGPUB; USPAT; USOCR
11	L13	88758	imag\$3 near sens\$3	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
12	L14	173	5 and 13	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
13	L15	168	CMOS and 14	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	L #	Hits	Search Text	DBs
14	L16	162624 9	(solid near state) or semiconductor	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
15	L17	165	14 and 16	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B